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Dkt.06080

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

PCT

WERNER BENCH

Serial No.: 10/586,946

Filed: July 25, 2006

For: SEMICONDUCTOR STRUCTURE COMPRISING ACTIVE ZONES

INFORMATION DISCLOSURE STATEMENT

Honorable Commissioner for Patents
P.O. Box 1450
Alexandria, Virginia 22313-1450

Sir:

Applicant submits herewith a Form PTO-1449 listing references for consideration by the Examiner, together with copies of non-U.S. patent references.

Respectfully submitted,

Ira J. Schultz
Registration No. 28666

Form PTO-1449

ATTY DOCKET NO.
0608095APPLICATION NO.
10/586,946**INFORMATION DISCLOSURE CITATION
IN AN APPLICATION**

(Use several sheets if necessary)

APPLICANT
Werner BenschFILING DATE
July 25, 2006GROUP
PCT**PATENT DOCUMENTS**

EXAMINER INITIAL	DOCUMENT NUMBER							DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
	5	1	6	6	7	6	1	04/1998	Kimura et al			
	5	7	3	9	5	5	2	11/1992	Olson et al			
	2002	1	6	7	0	1	4	11/2002	Schlereth et al			
	2005	0	6	7	6	2	7	03/2005	Guangdi			

FOREIGN PATENT DOCUMENTS

DOCUMENT NUMBER							DATE	COUNTRY	CLASS	SUB CLASS	TRANSLATION	
											YES	NO
0	7	2	7	8	3	0	08/1996	EP				
0	6	4	9	2	0	2	02/1997	EP				
1	4	0	3	9	3	5	03/2004	EP				
00	7	7	8	6	1		12/2000	WO				

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

Ozden et al, "A Dual-Wavelength Indium Gallium Nitride Quantum Well Light Emitting Diode", Applied Physics Letters 0003-6951, Vo. 79, No. 16, 2001, pp. 2532-2534.

EXAMINER

/Shouxiang Hu/

DATE CONSIDERED

01/30/2009

EXAMINER: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.